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MOS INTEGRATED CIRCUIT $\mu PD720114$

ECOUSB[™] Series USB 2.0 HUB CONTROLLER



The μ PD720114 is a USB 2.0 hub device that complies with the Universal Serial Bus (USB) Specification Revision 2.0 and works up to 480 Mbps. USB 2.0 compliant transceivers are integrated for upstream and all downstream ports. The μ PD720114 works backward compatible either when any one of the downstream ports is connected to a USB 1.1 compliant device, or when the upstream port is connected to a USB 1.1 compliant host.

Detailed function descriptions are provided in the following user's manual. Be sure to read the manual before designing. μ PD720114 User's Manual: R19UH0079E

FEATURES

- Compliant with Universal Serial Bus Specification Revision 2.0 (Data Rate 1.5/12/480 Mbps)
- High-speed or full-speed packet protocol sequencer for Endpoint 0/1
- 4 (Max.) downstream facing ports
- Low power consumption (10 μA when hub in idle status, 149 mA when all parts run in HS mode)
- All downstream facing ports can handle high-speed (480 Mbps), full-speed (12 Mbps), and low-speed (1.5 Mbps) transaction.
- Supports split transaction to handle full-speed and low-speed transaction on downstream facing ports when Hub controller is working in high-speed mode.
- One Transaction Translator per Hub and supports four non-periodic buffers
- · Supports self-powered and bus-powered mode
- · Supports individual or global over-current detection and individual or ganged power control
- Supports downstream port status with LED
- Supports non-removable devices by I/O pin configuration
- Support Energy Star for PC peripheral system
- On chip Rpu, Rpd resistors and regulator (for core logic)
- Use 30 MHz crystal
- 3.3 V power supply

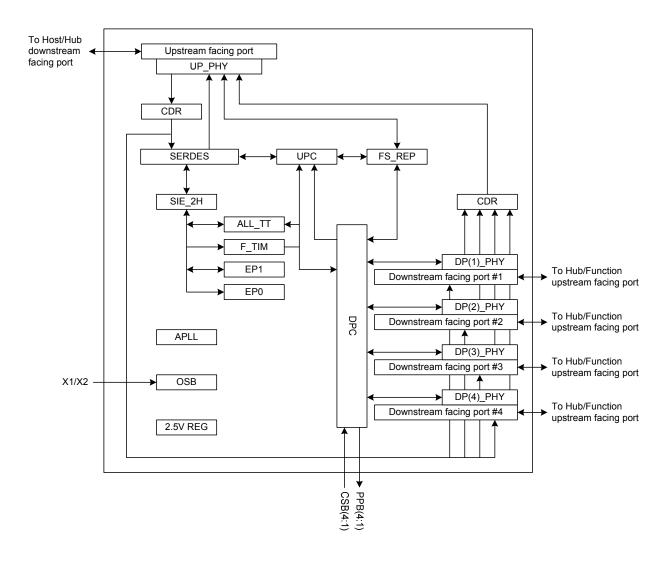
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ORDERING INFORMATION

	Part Number	Package	Remark	
	μPD720114GA-9EU-A	48-pin plastic TQFP (Fine pitch) (7×7)	Lead-free product	
	μPD720114GA-YEU-A	48-pin plastic TQFP (Fine pitch) (7×7)	Lead-free product	
<	R> μPD720114GA-YEU-AT	48-pin plastic TQFP (Fine pitch) (7×7)	Lead-free product	
	μPD720114K9-4E4-A	40-pin plastic QFN (6 \times 6)	Lead-free product	

BLOCK DIAGRAM



NEC μ PD720114

APLL : Generates all clocks of Hub.

ALL_TT : Translates the high-speed transactions (split transactions) for full/low-speed device

to full/low-speed transactions. ALL_TT buffers the data transfer from either upstream or downstream direction. For OUT transaction, ALL_TT buffers data from upstream port and sends it out to the downstream facing ports after speed conversion from high-speed to full/low-speed. For IN transaction, ALL_TT buffers data from downstream ports and sends it out to the upstream facing ports after

speed conversion from full/low-speed to high-speed.

CDR : Data & clock recovery circuit

DPC : Downstream Port Controller handles Port Reset, Enable, Disable, Suspend and

Resume

DP(n)_PHY : Downstream transceiver supports high-speed (480 Mbps), full-speed (12 Mbps), and

low-speed (1.5 Mbps) transaction

EP0 : Endpoint 0 controller
EP1 : Endpoint 1 controller

F_TIM (Frame Timer) : Manages hub's synchronization by using micro-SOF which is received at upstream

port, and generates SOF packet when full/low-speed device is attached to

downstream facing port.

FS REP : Full/low-speed repeater is enabled when the μ PD720114 are worked at full-speed

mode

OSB : Oscillator Block
2.5V REG : On chip 2.5V regulator

SERDES : Serializer and Deserializer

SIE_2H : Serial Interface Engine (SIE) controls USB2.0 and 1.1 protocol sequencer.

UP_PHY : Upstream Transceiver supports high-speed (480 Mbps), full-speed (12 Mbps)

transaction

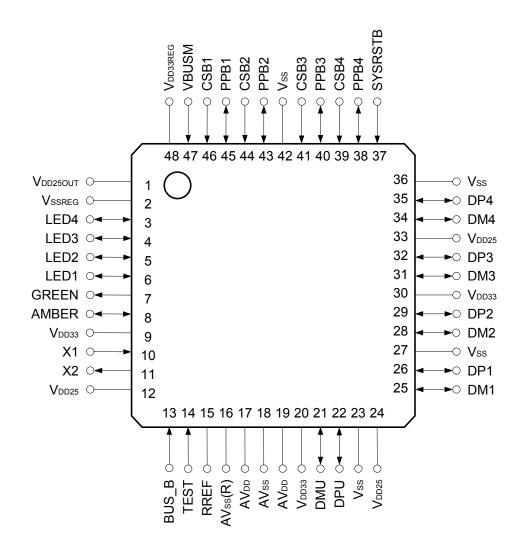
UPC : Upstream Port Controller handles Suspend and Resume



PIN CONFIGURATION (TOP VIEW)

• 48-pin plastic TQFP (Fine pitch) (7 × 7)

μPD720114GA-9EU-A μPD720114GA-YEU-A <R> μPD720114GA-YEU-AT



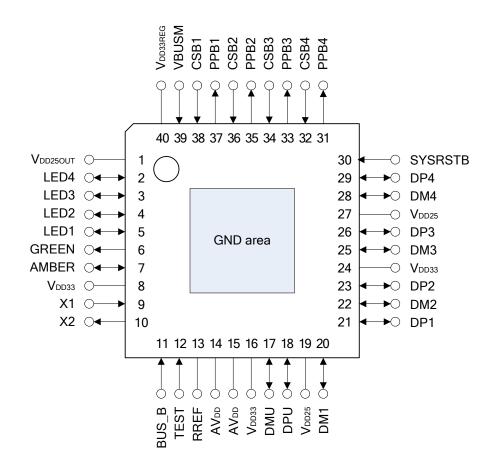


Pin No.	Pin Name	Pin No.	Pin Name	Pin No.	Pin Name	Pin No.	Pin Name
1	V _{DD25OUT}	13	BUS_B	25	DM1	37	SYSRSTB
2	Vssreg	14	TEST	26	DP1	38	PPB4
3	LED4	15	RREF	27	Vss	39	CSB4
4	LED3	16	AVss(R)	28	DM2	40	PPB3
5	LED2	17	AV _{DD}	29	DP2	41	CSB3
6	LED1	18	AVss	30	V _{DD33}	42	Vss
7	GREEN	19	AV _{DD}	31	DM3	43	PPB2
8	AMBER	20	V _{DD33}	32	DP3	44	CSB2
9	V _{DD33}	21	DMU	33	V _{DD25}	45	PPB1
10	X1	22	DPU	34	DM4	46	CSB1
11	X2	23	Vss	35	DP4	47	VBUSM
12	V _{DD25}	24	V _{DD25}	36	Vss	48	V _{DD33REG}

Remark AVss(R) should be used to connect RREF through 1 % precision reference resistor of 2.43 k Ω .

• 40-pin plastic QFN (6 × 6)

 μ PD720114K9-4E4-A



Pin No.	Pin Name	Pin No.	Pin Name	Pin No.	Pin Name	Pin No.	Pin Name
1	V _{DD25OUT}	11	BUS_B	21	DP1	31	PPB4
2	LED4	12	TEST	22	DM2	32	CSB4
3	LED3	13	RREF	23	DP2	33	PPB3
4	LED2	14	AV _{DD}	24	V _{DD33}	34	CSB3
5	LED1	15	AV _{DD}	25	DM3	35	PPB2
6	GREEN	16	V _{DD33}	26	DP3	36	CSB2
7	AMBER	17	DMU	27	V _{DD25}	37	PPB1
8	V _{DD33}	18	DPU	28	DM4	38	CSB1
9	X1	19	V _{DD25}	29	DP4	39	VBUSM
10	X2	20	DM1	30	SYSRSTB	40	V _{DD33REG}

Remark RREF should be connected to ground through 1% precision reference resistor of 2.43 k Ω .



1. PIN INFORMATION

Pin Name	I/O	Buffer Type	Active Level	Function
X1	I	2.5 V input		30 MHz Crystal oscillator in
X2	0	2.5 V output		30 MHz Crystal oscillator out
SYSRSTB	1	3.3 V Schmitt input	Low	Asynchronous chip hardware reset
DP(4:1)	I/O	USB D+ signal I/O		USB's downstream facing port D+ signal
DM(4:1)	I/O	USB D- signal I/O		USB's downstream facing port D- signal
DPU	I/O	USB D+ signal I/O		USB's upstream facing port D+ signal
DMU	I/O	USB D- signal I/O		USB's upstream facing port D- signal
BUS_B	1	3.3 V Schmitt input		Power mode select
RREF	A (O)	Analog		Reference resistor connection
CSB1	1	5 V tolerant Schmitt input	Low	Port's over-current status input.
CSB(4:2)	1	3.3 V Schmitt input	Low	Port's over-current status input
PPB(4:1)	I/O	3.3 V output / input	Low	Port's power supply control output or hub configuration input
VBUSM	1	5 V tolerant Schmitt input		Upstream V _{BUS} monitor
AMBER	I/O	3.3V output / input		Amber colored LED control output or port indicator select
GREEN	0	3.3V output		Green colored LED control output or port indicator select
LED(4:1)	I/O	3.3V output / input	Low	LED indicator output show downstream port status or Removable/Non-removable select
TEST	1	3.3 V Schmitt input		Test signal
VDD25OUT				On chip 2.5 V regulator output, it must have a 22 μ F (or greater) capacitor to Vsshed
V _{DD33}				3.3 V V _{DD}
VDD33REG				3.3 V V _{DD} for on chip 2.5 V regulator input, it must have a 4.7 μ F (or greater) capacitor to V _{SSREG}
V _{DD25}				2.5 V V _{DD} . These pins must be supplied from V _{DD25OUT} , output from internal regulator
AV _{DD}				2.5 V V _{DD} for analog circuit
Vss				Vss
Vssreg				On chip 2.5 V regulator Vss
AVss				Vss for analog circuit
AVss(R)				Vss for reference resistor, Connect to AVss.

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 $\textbf{Remark} \quad \text{``5 V tolerant'' means that the buffer is 3 V buffer with 5 V tolerant circuit.}$



2. ELECTRICAL SPECIFICATIONS

2.1 Buffer List

• 2.5 V Oscillator interface

X1, X2

• 5 V tolerant Schmitt input buffer

CSB1, VBUSM

• 3.3 V Schmitt input buffer

CSB(4:2),BUS_B, SYSRSTB, TEST

• 3.3 V IoL = 12 mA output buffer

GREEN

• 3.3 V input and 3.3 V loL = 3 mA output buffer

PPB(4:1), LED(4:1)

• 3.3 V input and loL = 12 mA output buffer

AMBER

USB2.0 interface

DPU, DMU, DP(4:1), DM(4:1), RREF

Above, "5 V" refers to a 3 V input buffer that is 5 V tolerant (has 5 V maximum input voltage). Therefore, it is possible to have a 5 V connection for an external bus.



2.2 Terminology

Terms Used in Absolute Maximum Ratings

Parameter	Symbol	Meaning
Power supply voltage	V _{DD33} , V _{DD33REG}	Indicates voltage range within which damage or reduced reliability will not result when power is applied to a V_{DD} pin.
Input voltage	Vı	Indicates voltage range within which damage or reduced reliability will not result when power is applied to an input pin.
Output voltage	Vo	Indicates voltage range within which damage or reduced reliability will not result when power is applied to an output pin.
Output current	lo	Indicates absolute tolerance values for DC current to prevent damage or reduced reliability when current flows out of or into an output pin.
Operating temperature	TA	Indicates the ambient temperature range for normal logic operations.
Storage temperature	T _{stg}	Indicates the element temperature range within which damage or reduced reliability will not result while no voltage or current are applied to the device.

Terms Used in Recommended Operating Range

Parameter	Symbol	Meaning
Power supply voltage	VDD33, VDD33REG	Indicates the voltage range for normal logic operations to occur when $V_{\rm SS}=0$ V.
High-level input voltage	VIH	Indicates the voltage, applied to the input pins of the device, which indicates the high level state for normal operation of the input buffer. * If a voltage that is equal to or greater than the "Min." value is applied, the input voltage is guaranteed as high level voltage.
Low-level input voltage	VIL	Indicates the voltage, applied to the input pins of the device, which indicates the low level state for normal operation of the input buffer. * If a voltage that is equal to or less than the "Max." value is applied, the input voltage is guaranteed as low level voltage.
Hysteresis voltage	Vн	Indicates the differential between the positive trigger voltage and the negative trigger voltage.
Input rise time	tri	Indicates allowable input rise time to input signal transition time from $0.1 \times V_{DD}$ to $0.9 \times V_{DD}$.
Input fall time	t fi	Indicates allowable input fall time to input signal transition time from $0.9 \times V_{DD}$ to $0.1 \times V_{DD}$.

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Terms Used in DC Characteristics

Parameter	Symbol	Meaning
Off-state output leakage current	loz	Indicates the current that flows into a 3-state output pin when it is in a high-impedance state and a voltage is applied to the pin.
Output short circuit current	los	Indicates the current that flows from an output pin when it is shorted to GND pins.
Input leakage current	li	Indicates the current that flows into an input pin when a voltage is applied to the pin.
Low-level output current	loL	Indicates the current that flows to the output pins when the rated low-level output voltage is being applied.
High-level output current	Іон	Indicates the current that can flow out of an output pin in the high-level state without reducing the output voltage below the specified Voh. (A negative current indicates current flowing out of the pin.)



2.3 Electrical Specifications

Absolute Maximum Ratings

Parameter	Symbol	Condition	Rating	Unit
Power supply voltage	VDD33,VDD33REG		-0.5 to +4.6	V
Input/output voltage	V _I /V _O			
3.3 V input/output voltage		3.0 V ≤ V _{DD33} ≤ 3.6 V V _I /V _O < V _{DD33} + 1.0 V	-0.5 to +4.6	V
5 V input/out voltage		$3.0 \text{ V} \le \text{V}_{\text{DD33}} \le 3.6 \text{ V}$ V ₁ /V ₀ < V _{DD33} + 3.0 V	-0.5 to +6.6	V
Output current	lo	IoL = 3 mA IoL = 12 mA	10 40	mA mA
Operating temperature	ТА		0 to +85	°C
Storage temperature	T _{stg}		-65 to +150	°C

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameters. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.

The ratings and conditions indicated for DC characteristics and AC characteristics represent the quality assurance range during normal operation.

Recommended Operating Ranges

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Operating voltage	VDD33,VDD33REG	3.3 V for V _{DD33} pins	3.14	3.30	3.46	V
High-level input voltage	ViH					
3.3 V High-level input voltage			2.0		V _{DD33}	V
5.0 V High-level input voltage			2.0		5.5	٧
Low-level input voltage	VIL					
3.3 V Low-level input voltage			0		0.8	V
5.0 V Low-level input voltage			0		0.8	٧
Hysteresis voltage	Vн					
5 V Hysteresis voltage			0.3		1.5	٧
3.3 V Hysteresis voltage			0.2		1.0	V
Input rise time for SYSRSTB	trst				10	ms
Input rise time	tri					
Normal buffer			0		200	ns
Schmitt buffer			0		10	ms
Input fall time	t fi					
Normal buffer			0		200	ns
Schmitt buffer			0		10	ms

Data Sheet R19DS0076EJ0700



DC Characteristics (V_{DD33} = 3.14 to 3.46 V, T_A = 0 to +70 °C)

Control Pin Block

Parameter	Symbol	Condition	Min.	Max.	Unit
Off-state output leakage current	loz	Vo = VDD33, VDD25 Or VSS		±10	μΑ
Output short circuit current	Note los			-250	mA
Low-level output current	loL				
3.3 V low-level output current (3 mA)		Vol = 0.4 V	3		mA
3.3 V low-level output current (12 mA)		Vol = 0.4 V	12		mA
High-level output current	Іон				
3.3 V high-level output current (3 mA)		Vон = 2.4 V	-3		mA
3.3 V high-level output current (12 mA)		Vон = 2.4 V	-12		mA
Input leakage current	lı				
3.3 V buffer		VI = VDD or Vss		±10	μΑ
5.0 V buffer		VI = VDD or Vss		±10	μΑ

Note The output short circuit time is measured at one second or less and is tested with only one pin on the LSI.



USB Interface Block

Parameter	Symbol	Conditions	Min.	Max.	Unit
Output pin impedance	ZHSDRV	Includes Rs resistor	40.5	49.5	Ω
Termination voltage for upstream facing port pullup (full-speed)	VTERM		3.0	3.6	V
Input Levels for Low-/full-speed:					
High-level input voltage (drive)	VIH		2.0		٧
High-level input voltage (floating)	VIHZ		2.7	3.6	V
Low-level input voltage	VIL			0.8	٧
Differential input sensitivity	V _{DI}	(D+) – (D–)	0.2		V
Differential common mode range	Vсм	Includes V _{DI} range	0.8	2.5	٧
Output Levels for Low-/full-speed:					
High-level output voltage	Vон	R _L of 14.25 kΩ to GND	2.8	3.6	V
Low-level output voltage	Vol	R _L of 1.425 kΩ to 3.6 V	0.0	0.3	V
SE1	Vose1		0.8		V
Output signal crossover point voltage	Vcrs		1.3	2.0	V
Input Levels for High-speed:					
High-speed squelch detection threshold (differential signal)	VHSSQ		100	150	mV
High-speed disconnect detection threshold (differential signal)	VHSDSC		525	625	mV
High-speed data signaling common mode voltage range	VHSCM		-50	+500	mV
High-speed differential input signaling levels	See Figure 2	2-4.	1		
Output Levels for High-speed:	•				
High-speed idle state	VHSOI		-10.0	+10	mV
High-speed data signaling high	VHSOH		360	440	mV
High-speed data signaling low	VHSOL		-10.0	+10	mV
Chirp J level (different signal)	VCHIRPJ		700	1100	mV
Chirp K level (different signal)	VCHIRPK		-900	-500	mV

Figure 2-1. Differential Input Sensitivity Range for Low-/full-speed

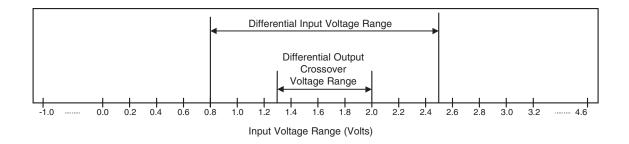


Figure 2-2. Full-speed Buffer Voн/Ioн Characteristics for High-speed Capable Transceiver

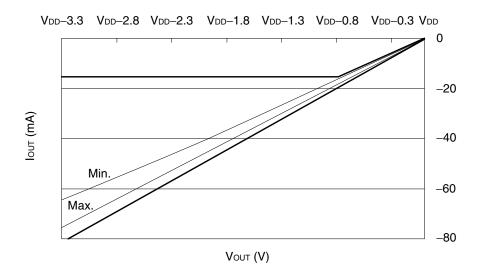
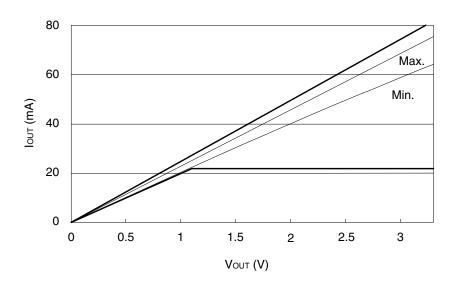


Figure 2-3. Full-speed Buffer Vol/lol Characteristics for High-speed Capable Transceiver



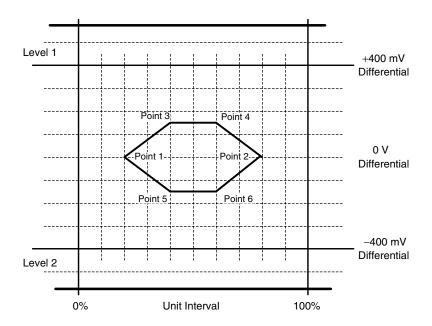
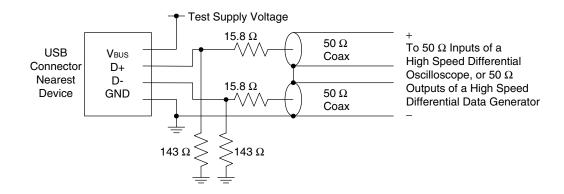


Figure 2-4. Receiver Sensitivity for Transceiver at DP/DM

Figure 2-5. Receiver Measurement Fixtures





Power Consumption

Parameter	Symbol	Condition	Тур.	Unit
Power Consumption	Pw-o	The power consumption under the state without suspend. All the ports do not connect to any function.		
		Hub controller is operating at full-speed mode. Hub controller is operating at high-speed mode.	31 86	mA mA
	Pw-2	The power consumption under the state without suspend. The number of active ports is 2. Note 2		
		Hub controller is operating at full-speed mode.	36	mA
		Hub controller is operating at high-speed mode.		mA
	Pw-3	Pw-3 The power consumption under the state without suspend. The number of active ports is 3.		
		Hub controller is operating at full-speed mode.	38	mA
		Hub controller is operating at high-speed mode.	134	mA
	Pw-4	The power consumption under the state without suspend. The number of active ports is 4. Note 2		
		Hub controller is operating at full-speed mode.	41	mA
		Hub controller is operating at high-speed mode.	149	mA
	Pw-unp	The power consumption under unplug and the hub in idle state.	10	μΑ
	Pw_s	The power consumption under plug (V _{BUS} ON) and the hub in suspend state.	220	μΑ

Notes 1. Ports available but inactive or unplugged do not add to the power consumption.

- 2. The power consumption depends on the number of ports available and actively operating.
- 3. If the μ PD720114 is locally powered and the upstream facing port is unplugged, μ PD720114 goes into suspend state and downstream facing port V_{BUS} goes down.
- 4. If the upstream V_{BUS} in OFF state, the power consumption is same as P_{W-UNP}.



AC Characteristics (V_{DD33} = 3.14 to 3.46 V, TA = 0 to +70 °C)

Pin capacitance

Parameter	Symbol	Condition	Min.	Max.	Unit
Input capacitance	Cı	V _{DD} = 0 V, T _A = 25 °C		6	pF
Output capacitance	Co	fc = 1 MHz		6	pF
I/O capacitance	Cio	Unmeasured pins returned to 0 V		6	pF

System Clock Ratings

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Clock frequency	fclk	Crystal	-500	30	+500	MHz
			ppm		ppm	
Clock Duty cycle	t DUTY		40	50	60	%

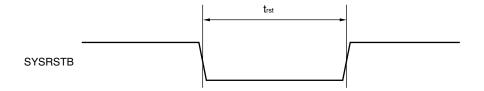
Remarks 1. Recommended accuracy of clock frequency is \pm 100 ppm.

2. Required accuracy of X'tal is including initial frequency accuracy, the spread of X'tal capacitor loading, supply voltage, temperature, and aging, etc.

System Reset Timing

Parameter	Symbol	Conditions	Min.	Max.	Unit
Reset active time (Figure 2-6)	trst		5		μs

Figure 2-6. System Reset Timing



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Over-current Response Timing

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Over-current response time from CSB low to PPB high (Figure 2-7)	toc		4		5	ms

Figure 2-7. Over-current Response Timing

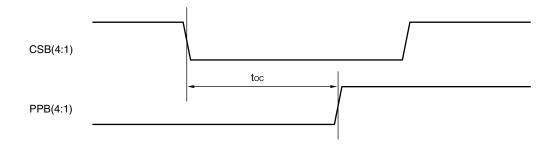
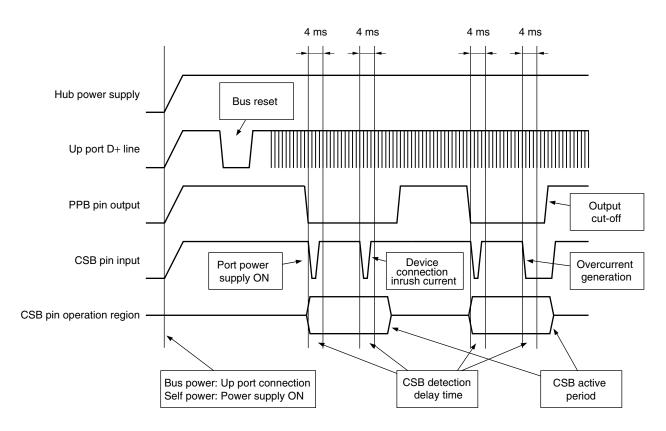


Figure 2-8. CSB/PPB Timing



Remark The active period of the CSB pin is in effect only when the PPB pin is ON.

There is a delay time of approximately 4 ms duration at the CSB pin.



USB Interface Block

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Parameter	Symbol	Conditions	Min.	Max.	Unit
Low-speed Electrical Characteristics					
Rise time (10% to 90%)	tlr	C _L = 200 pF to 600 pF	75	300	ns
Fall time (90% to 10%)	tlf	C _L = 200 pF to 600 pF	75	300	ns
Differential rise and fall time matching	turfm	(tlr/tlf) Note	80	125	%
Low-speed data rate	tldraths	Average bit rate	1.49925	1.50075	Mbps
Downstream facing port source jitter total (including frequency tolerance) (Figure 2-13): To next transition	tooji		-25	+25	ns
For paired transitions	t _{DDJ2}		-14	+14	ns
Downstream facing port differential receiver jitter total (including frequency tolerance) (Figure 2-15): To next transition	tuuri		-152	+152	ns
For paired transitions	tujr2		-200	+200	ns
Source SE0 interval of EOP (Figure 2-14)	t LEOPT		1.25	1.5	μs
Receiver SE0 interval of EOP (Figure 2-14)	t LEOPR		670		ns
Width of SE0 interval during differential transition	t lst			210	ns
Hub differential data delay (Figure 2-11)	t LHDD			300	ns
Hub differential driver jitter (including cable) (Figure 2-11):					
Downstream facing port To next transition For paired transitions Upstream facing port	tldhj1 tldhj2		-45 -15	+45 +15	ns ns
To next transition	t LUHJ1		-45	+45	ns
For paired transitions	tuhj2		-45	+45	ns
Data bit width distortion after SOP (Figure 2-11)	tlsop		-60	+60	ns
Hub EOP delay relative to thdd (Figure 2-12)	t LEOPD		0	200	ns
Hub EOP output width skew (Figure 2-12)	t LHESK		-300	+300	ns
Full-speed Electrical Characteristics					
Rise time (10% to 90%)	ter	$C_L = 50 \text{ pF},$ $R_S = 36 \Omega$	4	20	ns
Fall time (90% to 10%)	trr	$C_L = 50 \text{ pF},$ $R_S = 36 \Omega$	4	20	ns
Differential rise and fall time matching	t FRFM	(tfr/tff)	90	111.11	%
Full-speed data rate	t fdraths	Average bit rate	11.9940	12.0060	Mbps
Frame interval	t FRAME		0.9995	1.0005	ms

Note Excluding the first transition from the Idle state.

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Parameter	Symbol	Conditions	Min.	Max.	Unit
Full-speed Electrical Characteristics (Conti	nued)				
Consecutive frame interval jitter	trfi	No clock adjustment		42	ns
Source jitter total (including frequency tolerance) (Figure 2-13): To next transition	t _{DJ1}	Note	-3.5	+3.5	ns
For paired transitions	t _{DJ2}		-4.0	+4.0	ns
Source jitter for differential transition to SE0 transition (Figure 2-14)	t FDEOP		-2	+5	ns
Receiver jitter (Figure 2-15): To Next Transition For Paired Transitions	turi turi		-18.5 -9	+18.5 +9	ns ns
Source SE0 interval of EOP (Figure 2-14)	t _{FEOPT}		160	175	ns
Receiver SE0 interval of EOP (Figure 2-14)	treopr treopr		82	175	
Width of SE0 interval during differential transition	treoph		02	14	ns
Hub differential data delay (Figure 2-11) (with cable) (without cable)	thdd1 thdd2			70 44	ns ns
Hub differential driver jitter (including cable) (Figure 2-11):					
To next transition For paired transitions	thdui thdui		−3 −1	+3 +1	ns ns
Data bit width distortion after SOP (Figure 2-11)	trsop		-5	+5	ns
Hub EOP delay relative to thdd (Figure 2-12)	t FEOPD		0	15	ns
Hub EOP output width skew (Figure 2-12)	t FHESK		-15	+15	ns
High-speed Electrical Characteristics					
Rise time (10% to 90%)	thsr		500		ps
Fall time (90% to 10%)	thsf		500		ps
Driver waveform	See Figure	2-9.	•	1	
High-speed data rate	thsdrat		479.760	480.240	Mbps
Microframe interval	thsfram		124.9375	125.0625	μs
Consecutive microframe interval difference	thsrFi			4 high- speed	Bit times
Data source jitter	See Figure	2-9.	•	•	
Receiver jitter tolerance	See Figure	2-4.			
Hub data delay (without cable)	thshdd			36 high- speed+4 ns	Bit times
Hub data jitter	See Figure	2-4, Figure 2-9.			
Hub delay variation range	thshov			5 high- speed	Bit times

Note Excluding the first transition from the Idle state.

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Parameter	Symbol	Conditions	Min.	Max.	Unit
Hub Event Timings					
Time to detect a downstream facing port connect event (Figure 2-17): Awake hub Suspended hub	†DCNN		2.5 2.5	2000 12000	μs μs
Time to detect a disconnect event at a hub's downstream facing port (Figure 2-16)	todis		2.0	2.5	μs
Duration of driving resume to a downstream port (only from a controlling hub)	torsmon		20		ms
Time from detecting downstream resume to rebroadcast	tursm			1.0	ms
Duration of driving reset to a downstream facing port (Figure 2-18)	t DRST	Only for a SetPortFeature (PORT_RESET) request	10	20	ms
Time to detect a long K from upstream	turlk		2.5	100	μs
Time to detect a long SE0 from upstream	turlse0		2.5	10000	μs
Duration of repeating SE0 upstream (for low-/full-speed repeater)	turpse0			23	FS Bit times
Inter-packet delay (for high-speed) of packets traveling in same direction	thsipdsd		88		Bit times
Inter-packet delay (for high-speed) of packets traveling in opposite direction	thsipdod		8		Bit times
Inter-packet delay for device/root hub response with detachable cable for high-speed	thsrspipd1			192	Bit times
Time of which a Chirp J or Chirp K must be continuously detected (filtered) by hub or device during Reset handshake	tғішт		2.5		μs
Time after end of device Chirp K by which hub must start driving first Chirp K in the hub's chirp sequence	twтосн			100	μs
Time for which each individual Chirp J or Chirp K in the chirp sequence is driven downstream by hub during reset	tоснвіт		40	60	μs
Time before end of reset by which a hub must end its downstream chirp sequence	tDCHSE0		100	500	μs
Time from internal power good to device pulling D+ beyond V _{IHZ} (Figure 2-18)	tsigatt			100	ms
Debounce interval provided by USB system software after attach (Figure 2-18)	tattdb			100	ms
Maximum duration of suspend averaging interval	tsusavgi			1	S
Period of idle bus before device can initiate resume	twtrsm		5		ms

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Symbol	Conditions	Min.	Max.	Unit
trsmrcy	Remote-wakeup is enabled	10		ms
†DETRST		2.5	10000	μs
trstrcy			10	ms
tiPD		2		Bit times
trspipd1			6.5	Bit times
tdsetaddr			50	ms
tdrqcmpltnd			50	ms
tdretdata1			500	ms
†DRETDATAN			50	ms
tfiltse0		2.5		μs
twtrstfs		2.5	3000	ms
twrrev		3.0	3.125	ms
twrвsтнs		100	875	ms
tucн		1.0		ms
tuchend			7.0	ms
twrns			500	μs
twrfs		1.0	2.5	ms
	trismacy triph tri	trasmacy Remote-wakeup is enabled toetrast trastracy trastracy traspipo1 tosetaddr toretdata1 toretdatan triltseo twiths tuch tuchend	tribution in the properties of	transprint tra

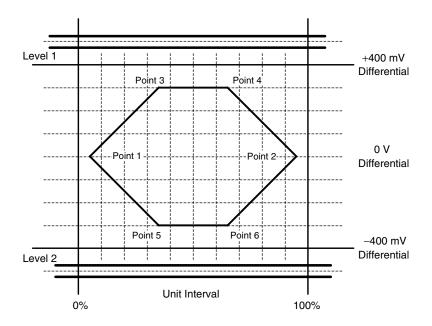


Figure 2-9. Transmit Waveform for Transceiver at DP/DM

Figure 2-10. Transmitter Measurement Fixtures

